

Limits on Reciprocity Failure in $1.7\mu\text{m}$ cut-off NIR astronomical detectors

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Detectors for Astronomy,
ESO Garching, 12-16 October 2009

Funding provided by



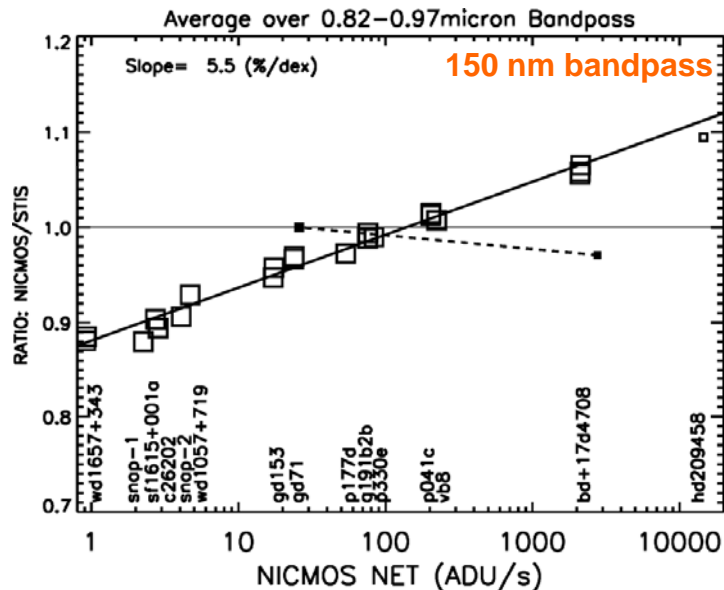
DE-FG02-08ER41566

The Need for Precision Photometry

- Recent discovery of **accelerated expansion** of universe has started revolution in cosmology
 - evidence from SNe, galaxies, galaxy clusters and CMB
 - implication: ~70% of universe is made of “**Dark Energy**”
 - very little is known about nature of Dark Energy:
 - Λ , quintessence, GR break down, higher dim, axions, etc
 - any option has profound implications
- To determine **nature** of Dark Energy is difficult task
 - combination of several observational techniques are needed:
 - SNe (standard candles), weak lensing, galaxy clusters, BAO
- Must rely on accurate distance measurements over cosmic scales
 - rely on **precise photometry** (1%-2% level)
- Photometric calibrations require observations of many standardized stars over a wide range of magnitude
 - rely on complete understanding of the **linearity** of the detectors

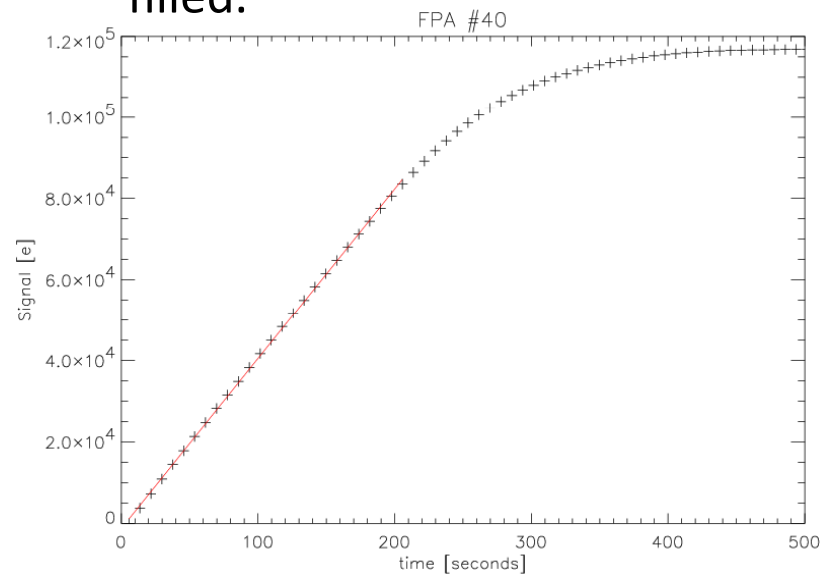
Reciprocity vs Saturation

- NICMOS arrays (2.5 μm cut-off HgCdTe) on HST exhibit a 5-6% \textbackslashdex flux dependent non-linearity



- exhibits power law behavior, with pixels with high count rates detecting slightly more flux than expected for a linear system (and vice-versa).

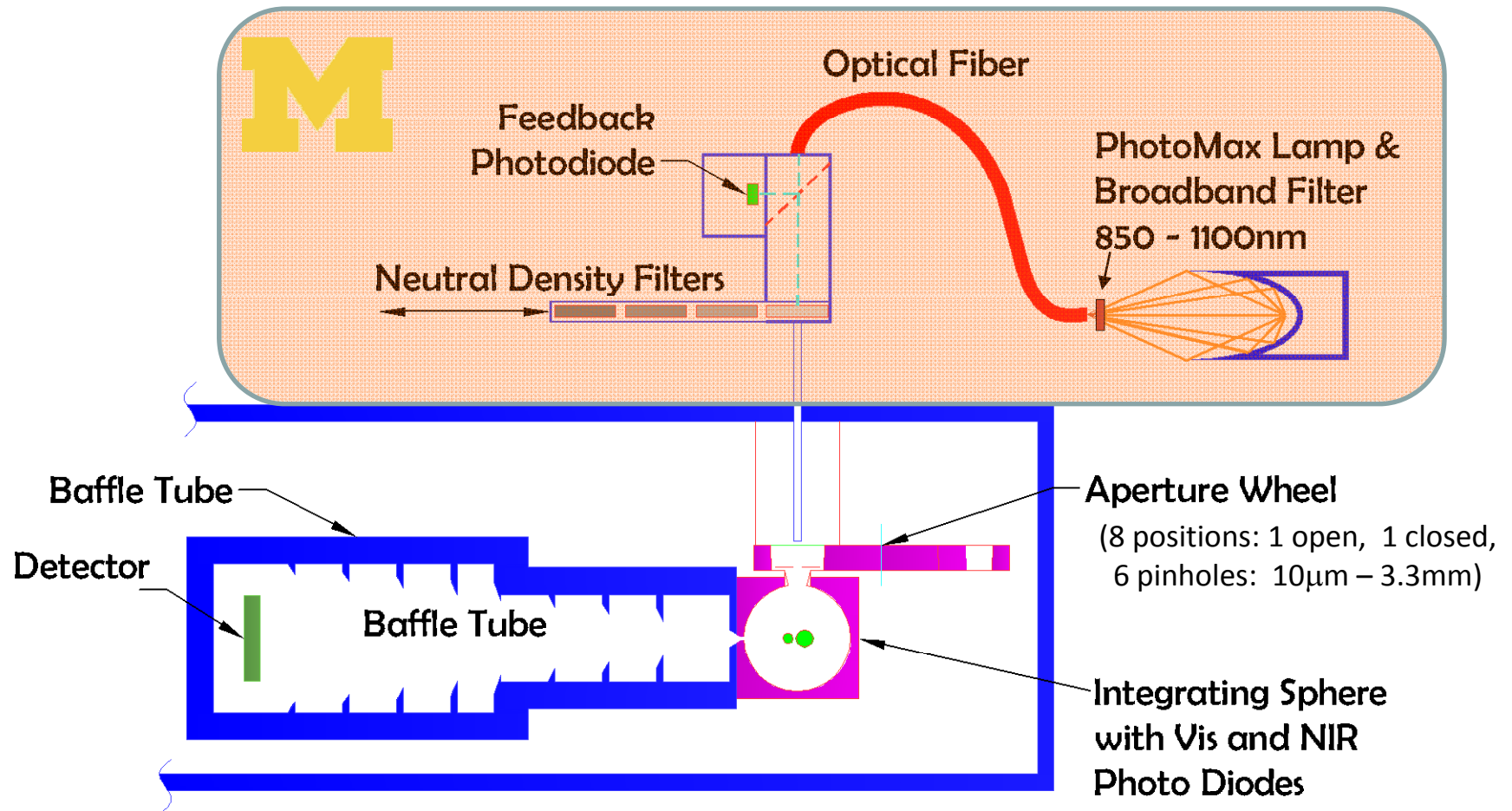
- distinctly different from well-known total count dependent non-linearity for NIR detectors that is due to saturation as well is filled.



- linearity is maintained within $\pm 3\%$ up to 80% of the full integration capacity

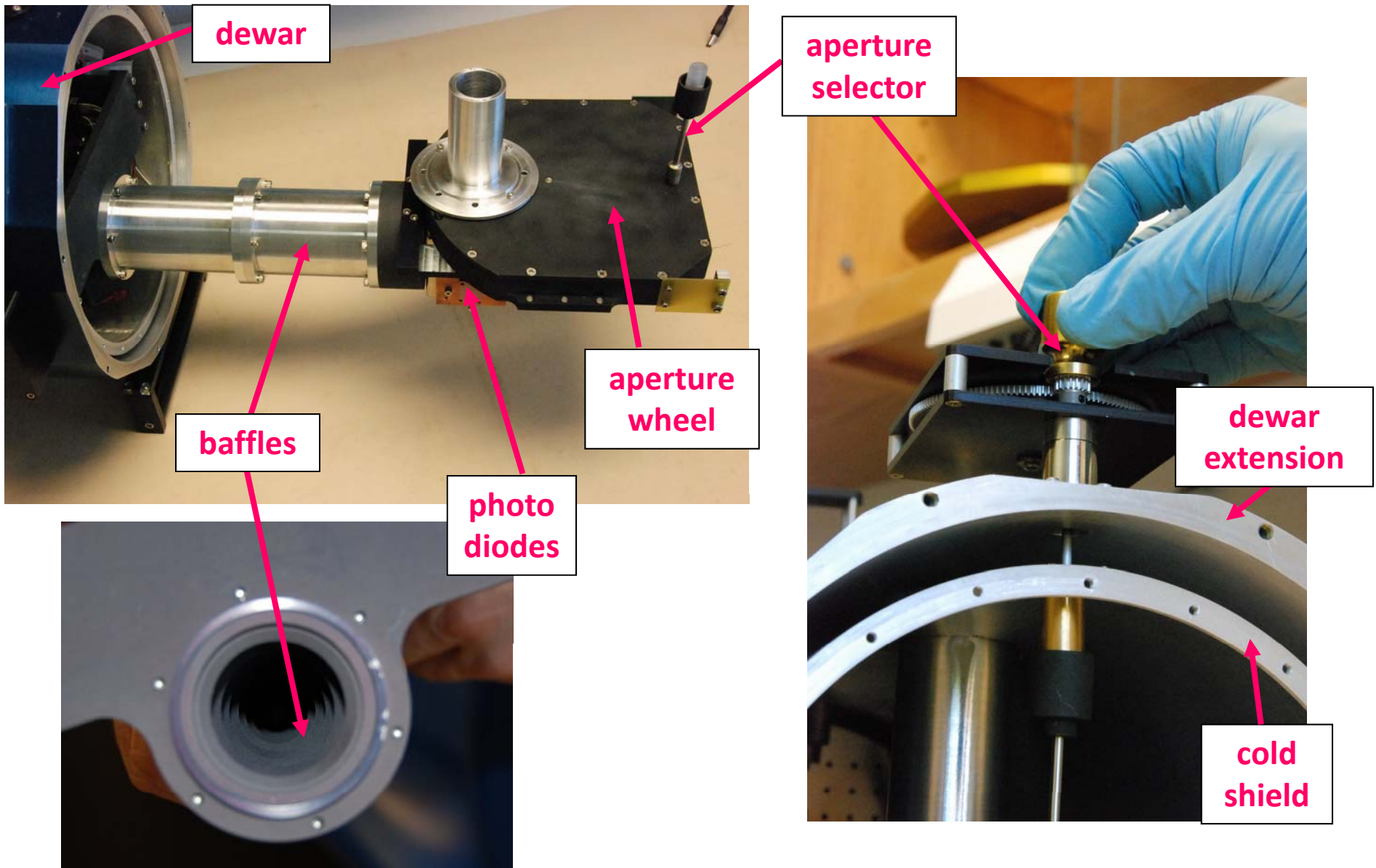
UM Reciprocity Setup

- Dewar extension attaches to existing IRLabs dewar



- no shutter required for HgCdTe (for CCDs shutter is important)

UM Reciprocity Setup



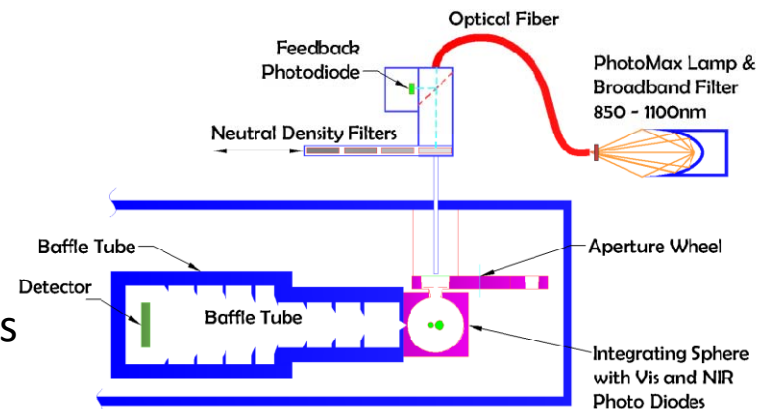
Reciprocity Measurement Scheme

Reciprocity measurement:

- use **fixed geometry** for detector and monitoring diodes
- sequence of **calibrated fluxes**
 - using photodiode (PD): independently shown to be **linear**
- Up-The-Ramp (UTR) images
 - take separate bias frame in dark and subtract that from the UTR images
- adjust **exposure time** to keep total count in detector constant
 - avoid standard detector non-linearity
- take **ratio** of average detector flux / PD current (**normalized detector flux**) and plot vs PD current (**count rate**)
- look for a $\sim 5\%/dex$ effect

Calibrations and studies:

- **PD linearity** with dynamic range: 10^5 w/ six pinholes
- **PD stability**: temp. stabilized at ~ 120 K
- **detector stability**: temp. stabilized at 140 K (± 10 mK)
- **Illumination stability**: temp. controlled feedback diode \rightarrow lamp output stable $< 0.1\%$
- persistence, timing, bias drifts, noise, frame-to-frame variations, long term drifts

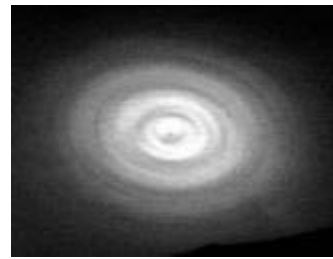


Challenges to reach good Repeatability

Illumination instabilities

- **New bellows**

- containment of stray light
- reproducibly position glass rod directly above pinhole
- But, glass rod produces illumination pattern on pinholes
- repeatability only at 5% level
 - tighten pinholes in changer
 - added diffusing sheets between rod and pinhole



- **Baffle tube**

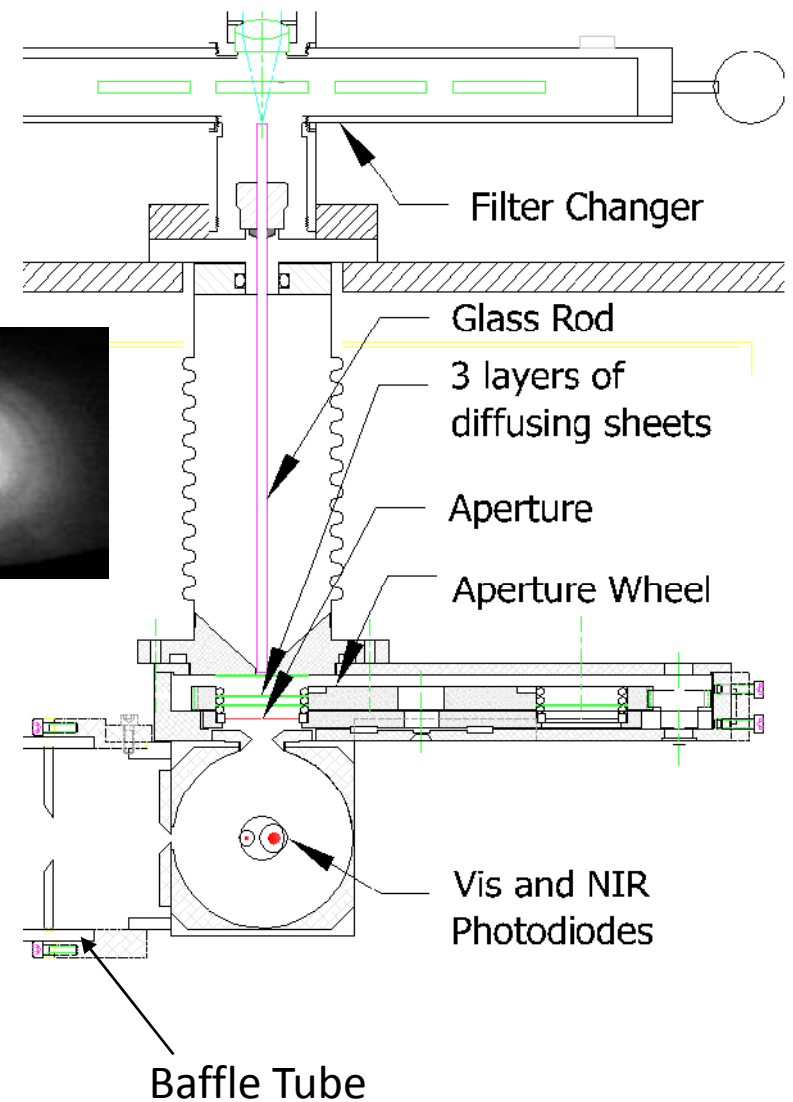
- Baffle tube bigger & close to detector
- Light tight box around detector

- **ND filter changer**

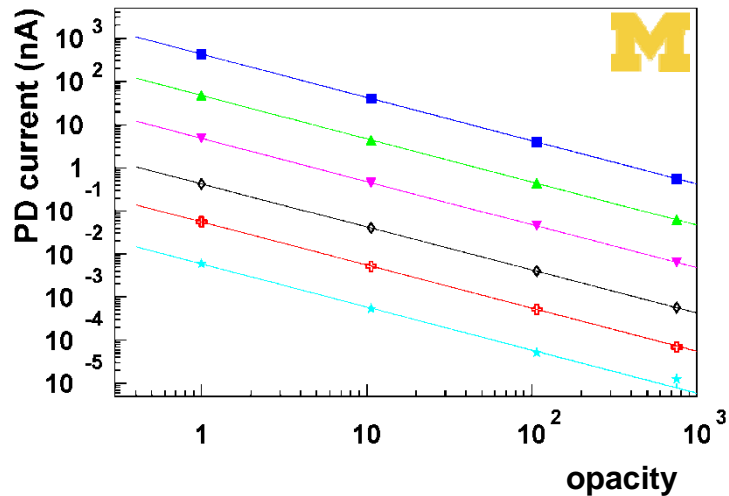
- repeatability only at 7% level
 - filter changer was clamped tightly

- **Lamp stabilization**

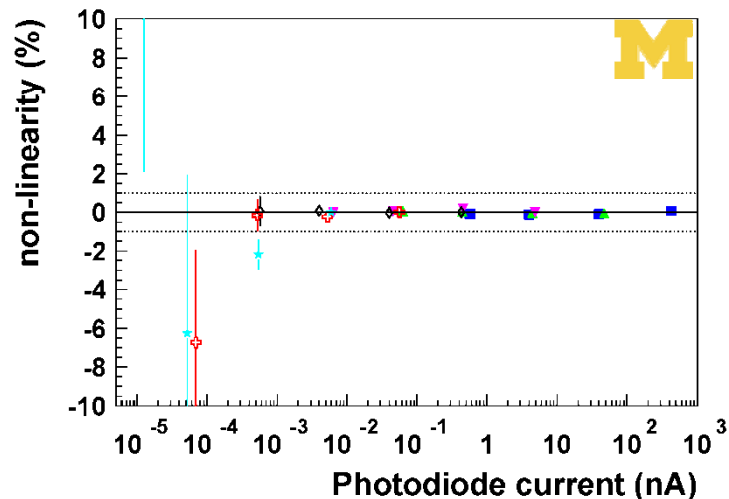
- Temp controlled feed back diode keeps lamp output stable <0.1%



Photodiode Linearity Calibration



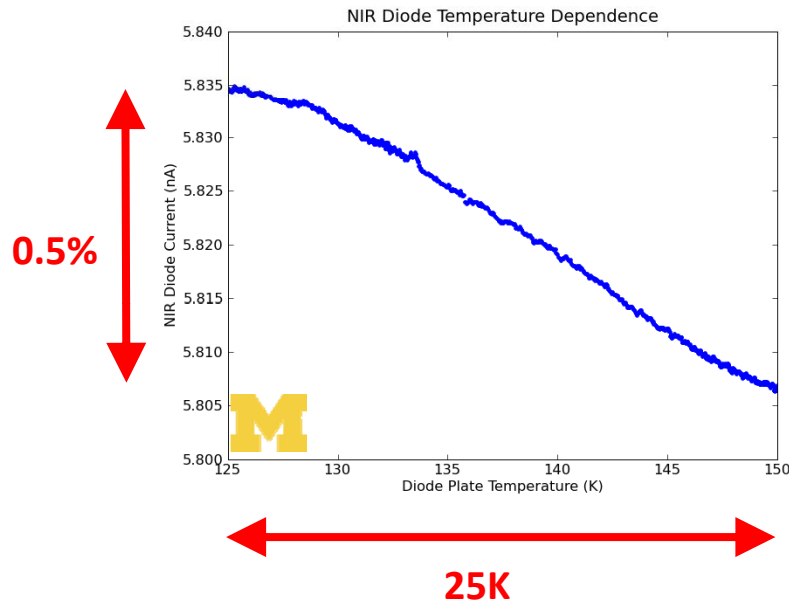
- Pinholes used: 3.3mm, 1.0mm, 333 μ m, 100 μ m, 33 μ m, 10 μ m
- Same slope fits data over $\sim 10^6$
- Lowest light levels have largest error; dominated by read noise in PD



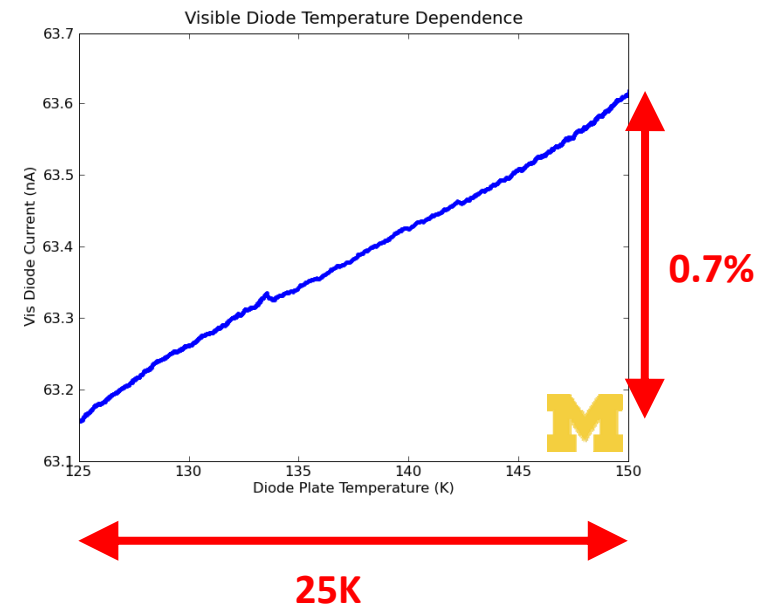
Deviation from linearity is better than $\pm 0.5\%$ over $\sim 10^5$ in light flux

Photodiode Stability

InGaAs (NIR) diode: G10899

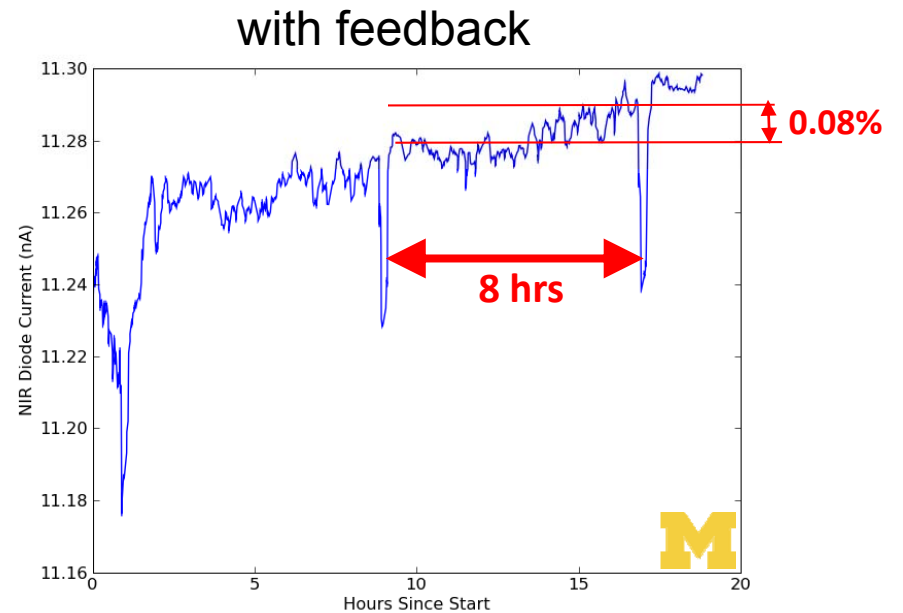
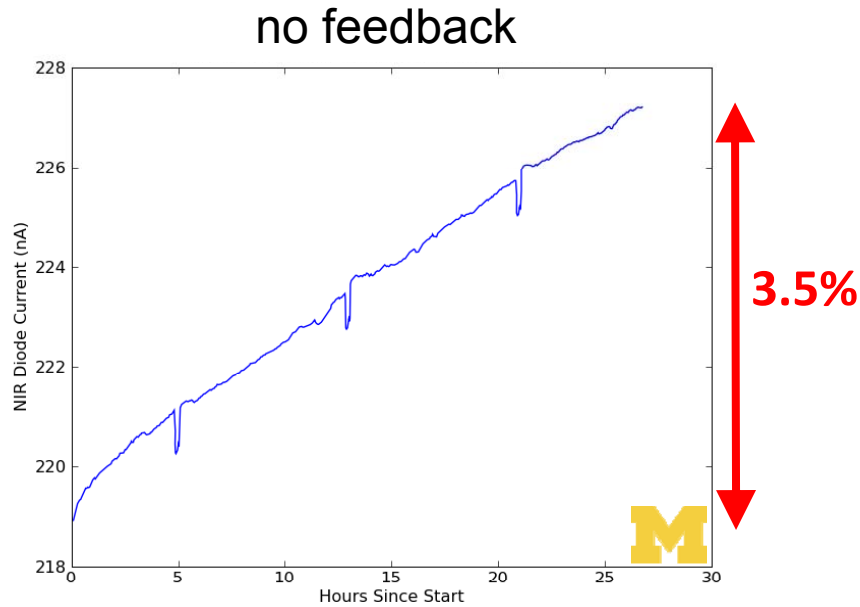


Silicon (visible) diode: NT53-371



- Data taken simultaneously
- The PDs display a temperature dependence of $< 0.1\%/K$
 - InGaAs and Silicon PDs: opposite behavior
- PDs temperature controlled to $< 1K$

Lamp Stability

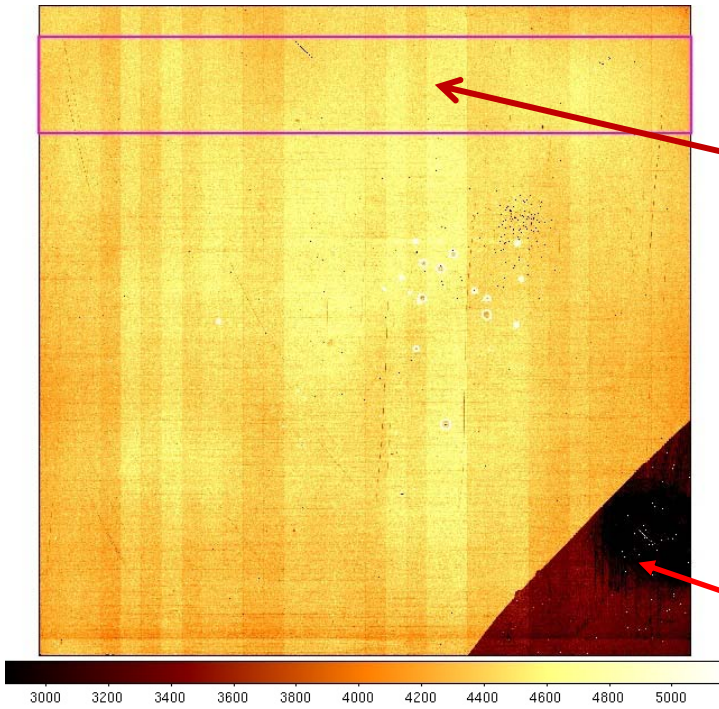


- quartz tungsten halogen lamp shows instabilities of $\sim 3.5\%$ over a 25 hr time interval (in constant current mode)
 - \rightarrow can be reduced to $< 0.1\%$ with active feedback over 8 hour period

Other Systematic Studies

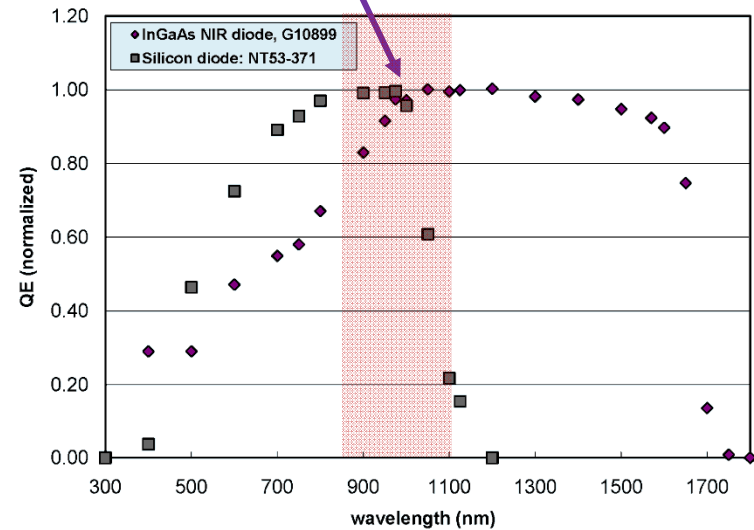
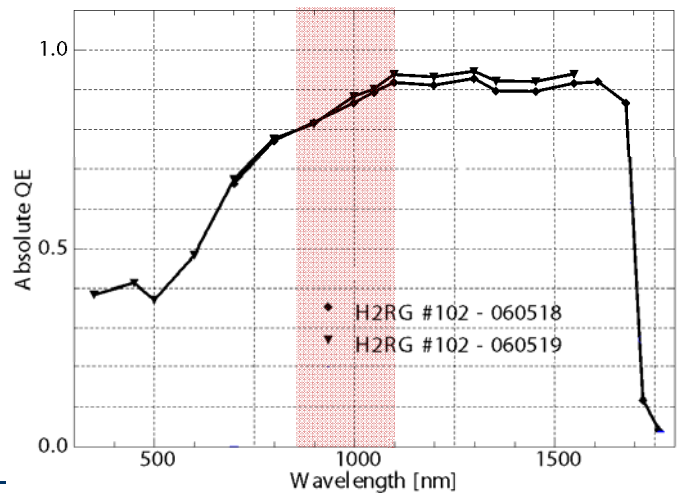
- **Light Leaks**
 - signal ports shielded
 - detector shielded → only 'sees' light from Integrating Sphere (IS)
- **Persistence**
 - go from low to high illumination (varying pin holes)
 - wait 30 min between each exposure sequence
- **Timing**
 - read time set in Voodoo needed to be calibrated (to <0.1%)
 - calibration 10 μ s (shortest read: 211 ms)
- **Long term drifts** (detector temp drift, electronics temp drift ?)
 - 'dark' reference diode tracks bias voltage drift
- **PD noise**
 - minimized by replacing cables (shorter and shielded)
- **Frame-to-frame variations** (probably bias voltage fluctuations)
 - tracked well by reference pixels
 - averaging many frames to reduce this noise
- **Aperture heating**
 - high light levels can heat up pin holes (glow in NIR PD detectable)
 - use gold coated pin holes (gold towards IS)
 - can be removed by using darks with light on

Detector Images (H2RG #102)

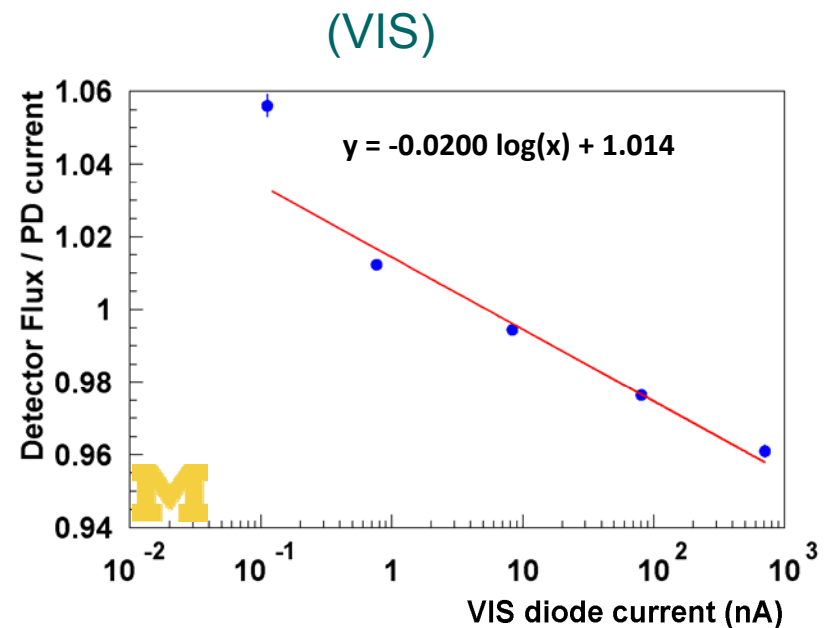
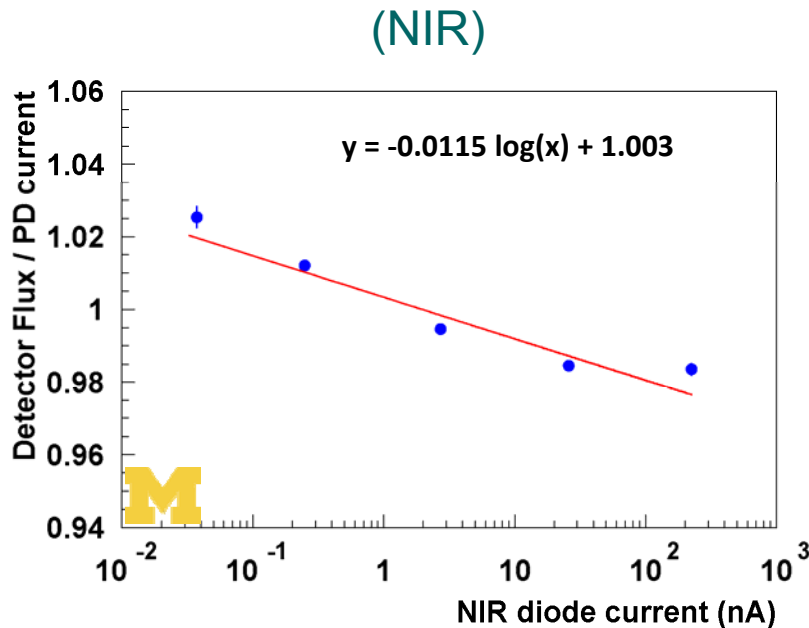


- fill well to about half of full well
- select region of
 - uniform QE
 - low on defects and hot pixels
- mask pixels that are 3σ above or below mean (4%)
 - 2% of pixels are clipped + adjacent pixels (2%)
- sum up all 'good' pixels
- divide by NIR PD signal (sensitivity well matched to detector)

No AR coating

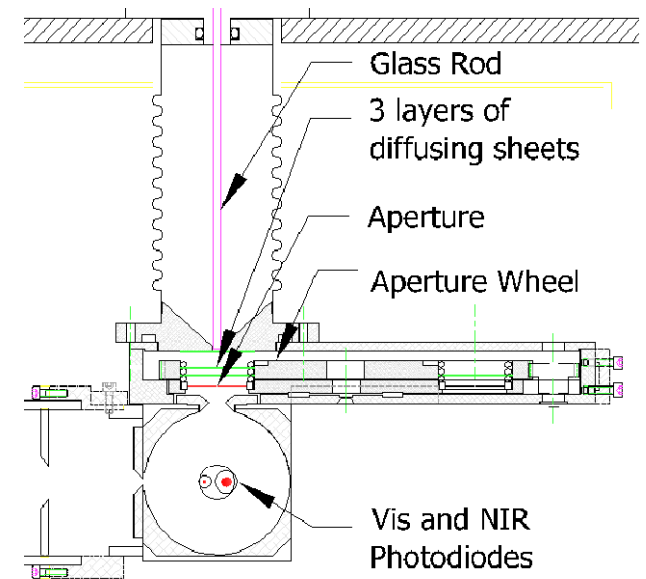
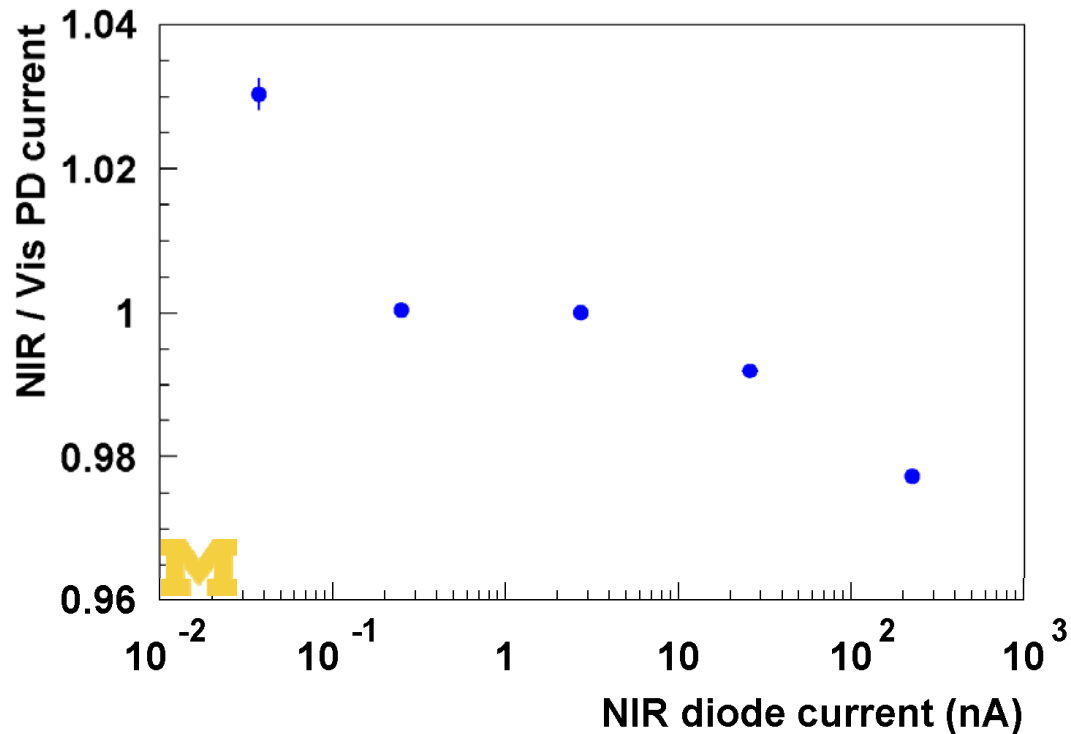


H2RG #102 Response



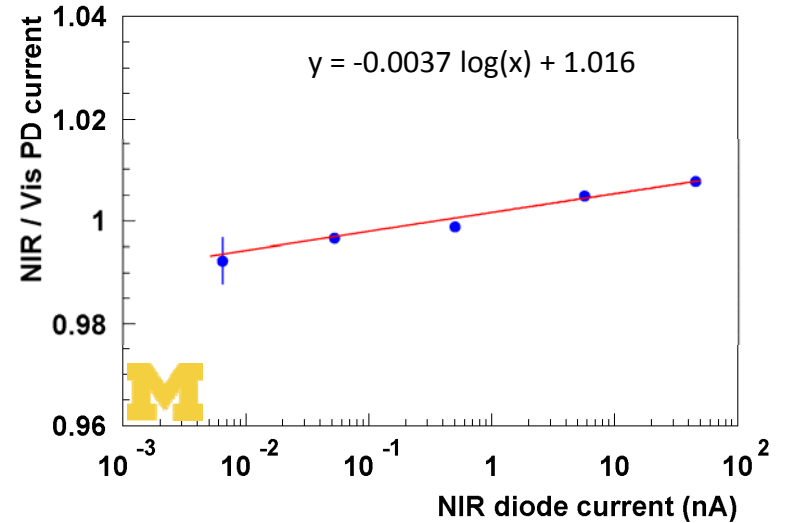
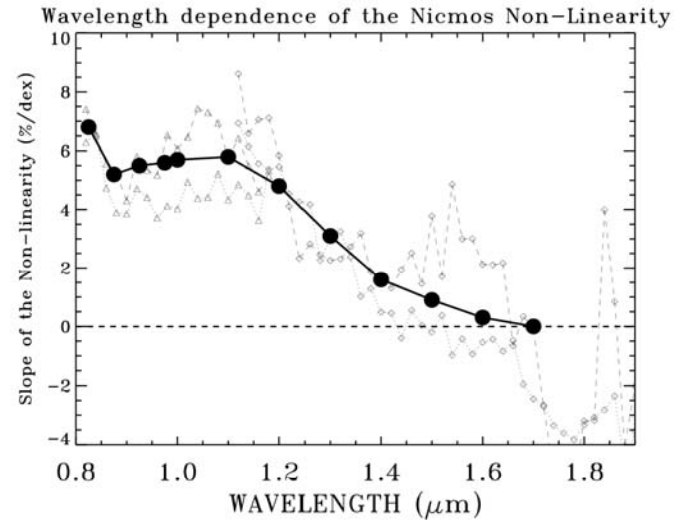
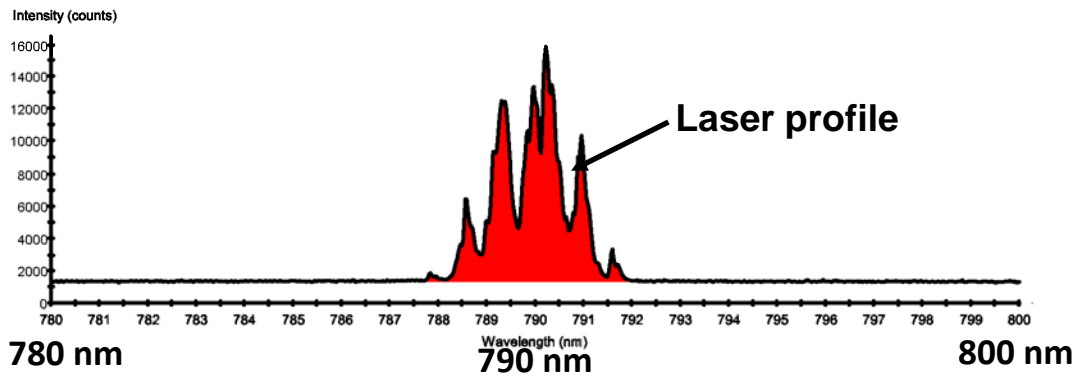
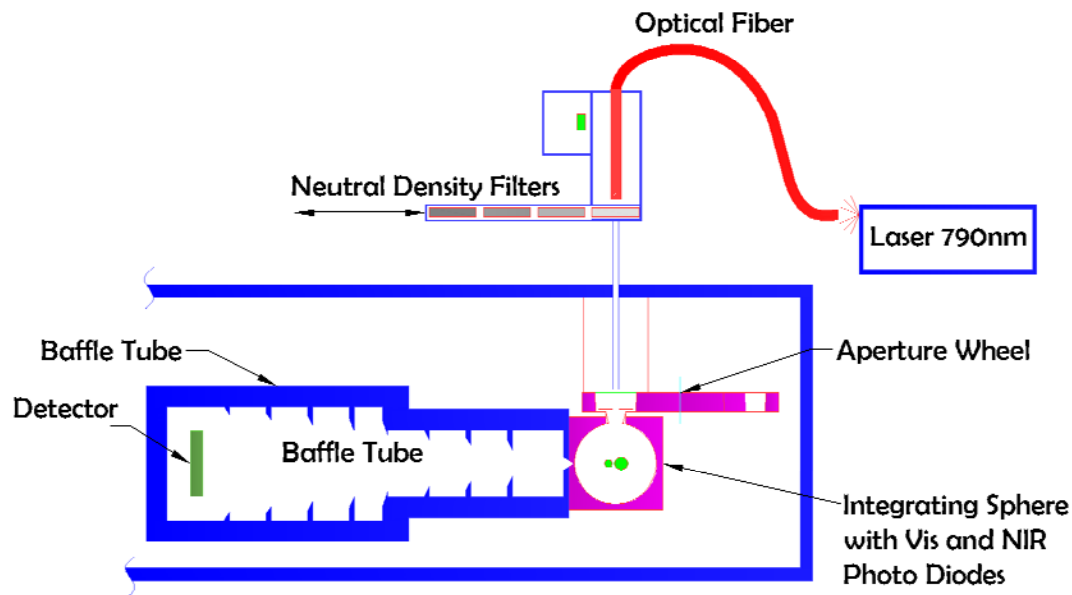
- The response of H2RG #102 (1.7 μm cut-off HgCdTe) **drops** by 1.2%/dex as input flux increases
 - opposite behavior to NICMOS 2.5 μm cut-off HgCdTe (5%/dex)
 - but much smaller effect
- When ratio taken vs visible PD → response drops by 2.0%/dex (twice as large!)
 - (NIR / Vis) PD signal must vary as input flux increases!

NIR / Vis PD Signal



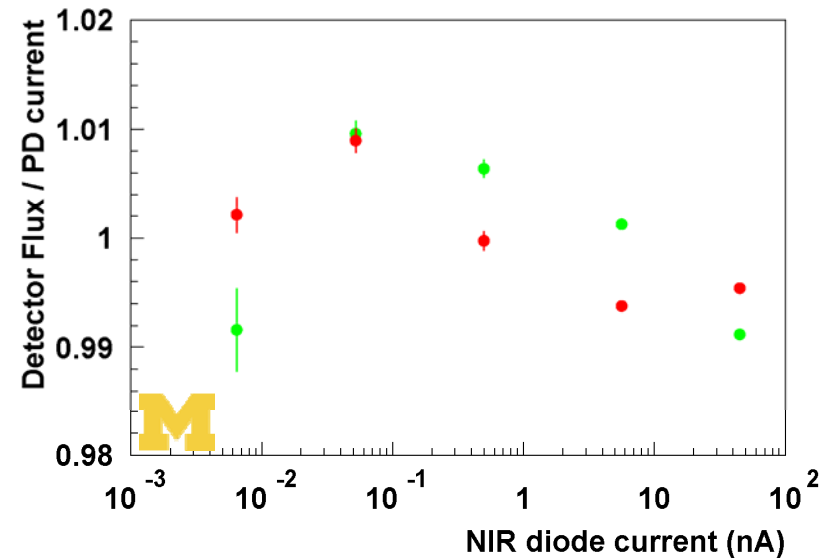
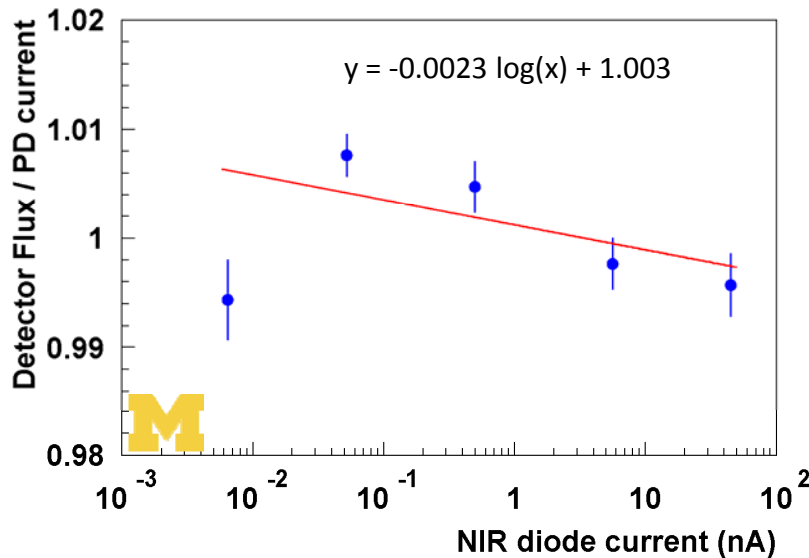
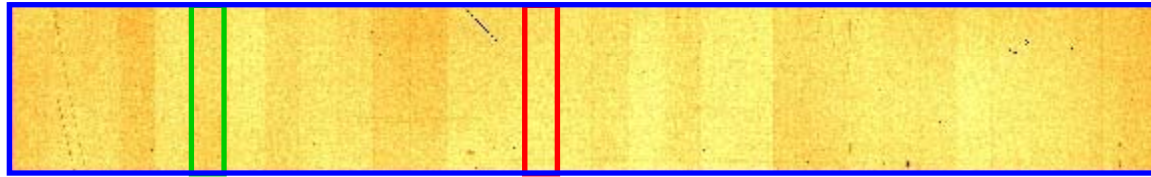
- (NIR / VIS) PD current varies with increasing light intensity (-1.3%/dex)
 - flip Vis & NIR diodes (geometrical effect): unchanged
 - replace Vis with 2nd NIR diode (spectral effect): improvement
 - replace 250nm with 50nm bandpass (spectral effect): improvement
 - replace lamp by narrow band laser

Reciprocity Setup with 790±1 nm Diode Laser



(NIR / VIS) PD current improves from $-1.3\%/dex \rightarrow +0.4\%/dex$

H2RG #102 Response

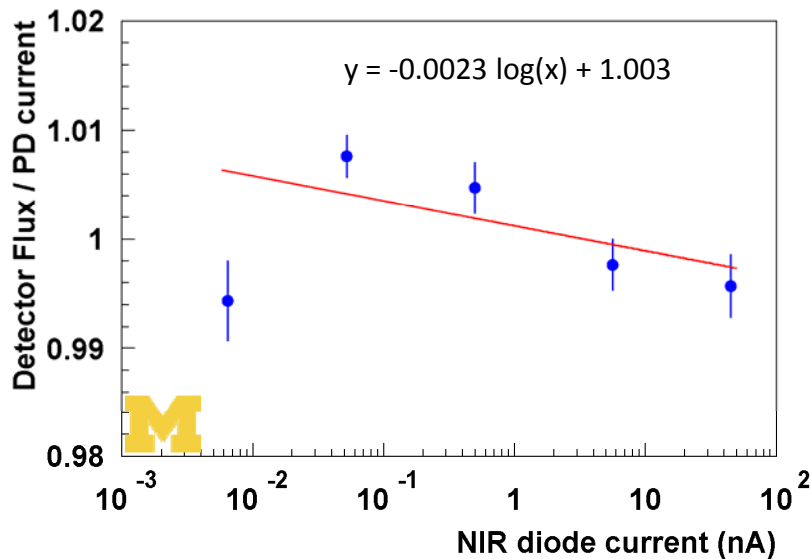


- The response of H2RG #102 (1.7 μm cut-off HgCdTe) exposed to narrow band laser light **drops** by $(0.23 \pm 0.1)\%$ /dex as input flux increases
→ but much smaller effect than with broad band (250 nm) filter
- Device shows some variations across the detector

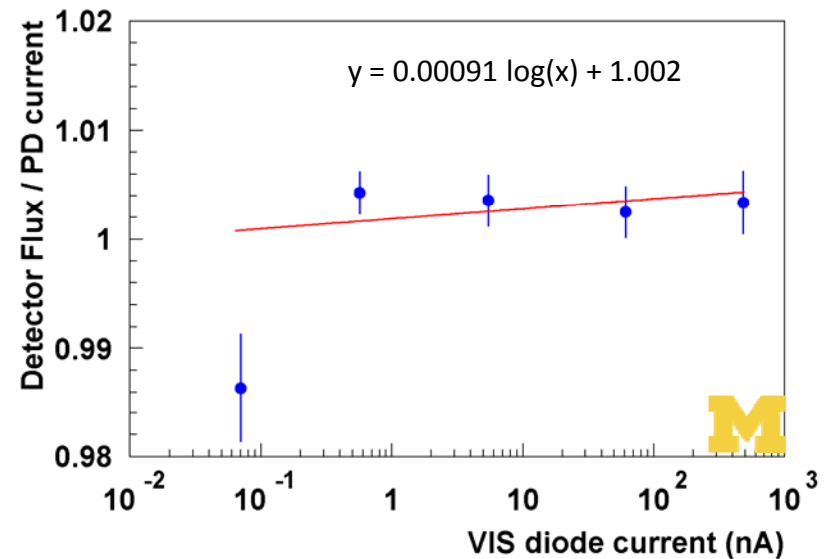
H2RG #102 Response



(NIR)



(VIS)



- The response of H2RG #102 (1.7 μm cut-off HgCdTe) is $(-0.23 \pm 0.1)\%/\text{dex}$ (NIR) and $(0.091 \pm 0.097)\%/\text{dex}$ (Vis) as input flux increases
 - slight difference between NIR and Vis PD calibrations
 - but overall smaller than $0.25\%/\text{dex}$

Summary and Outlook

- Reciprocity failure on a 1.7 μm HgCdTe detector appears $< 0.25\%/dex$
 - much smaller effect than seen on NICMOS
 - consistent with zero within precision of our apparatus
 - many studies performed on effects that could mimic reciprocity failure
- Will measure additional 1.7 μm HgCdTe detectors for reciprocity failure
 - use narrow band light source to perform studies
 - use lasers at different wave lengths to study wave length dependence
- Can be performed on HgCdTe, CCDs, ...
 - a detector specific mounting plate needs to be machined
 - allow for fast turn around time if detectors available
only for short time
 - ready for cross checking devices from DCL at GSFC